

## SPICE Device Model Si4404DY

## Vishay Siliconix

## N-Channel 30-V (D-S) MOSFET

#### **CHARACTERISTICS**

- N-Channel Vertical DMOS
- Macro Model (Subcircuit Model)
- Level 3 MOS

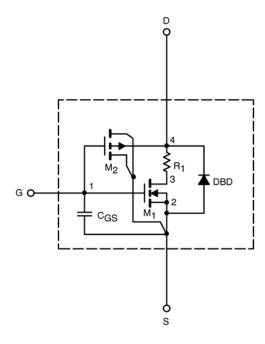
- Apply for both Linear and Switching Application
- Accurate over the -55 to 125°C Temperature Range
- Model the Gate Charge, Transient, and Diode Reverse Recovery Characteristics

#### **DESCRIPTION**

The attached spice model describes the typical electrical characteristics of the n-channel vertical DMOS. The subcircuit model is extracted and optimized over the -55 to  $125^{\circ}$ C temperature ranges under the pulsed 0-V to 10-V gate drive. The saturated output impedance is best fit at the gate bias near the threshold voltage.

A novel gate-to-drain feedback capacitance network is used to model the gate charge characteristics while avoiding convergence difficulties of the switched  $C_{\rm gd}$  model. All model parameter values are optimized to provide a best fit to the measured electrical data and are not intended as an exact physical interpretation of the device.

#### SUBCIRCUIT MODEL SCHEMATIC



This document is intended as a SPICE modeling guideline and does not constitute a commercial product data sheet. Designers should refer to the appropriate data sheet of the same number for guaranteed specification limits.

Document Number: 71650 www.vishay.com S-51095—Rev. B, 13-Jun-05

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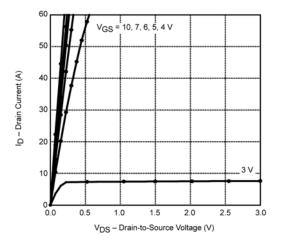
SPECIFICATIONS (T <sub>J</sub> = 25°C UNLESS OTHERWISE NOTED)					
Parameter	Symbol	Test Condition	Simulated Data	Measured Data	Unit
Static	•		•		
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}$ = $V_{GS}$ , $I_D$ = 250 $\mu A$	1.80		V
On-State Drain Current <sup>a</sup>	I <sub>D(on)</sub>	$V_{DS} \ge 5 \text{ V}, V_{GS} = 10 \text{ V}$	1196		Α
Drain-Source On-State Resistance <sup>a</sup>		V <sub>GS</sub> = 10 V, I <sub>D</sub> = 23 A	0.0036	0.004	Ω
	r <sub>DS(on)</sub>	$V_{GS}$ = 4.5 V, $I_{D}$ = 17 A	0.0059	0.0068	
Forward Transconductance <sup>a</sup>	9 <sub>fs</sub>	$V_{DS} = 15 \text{ V}, I_D = 23 \text{ A}$	55	80	S
Diode Forward Voltage <sup>a</sup>	$V_{SD}$	$I_S = 2.9 \text{ A}, V_{GS} = 0 \text{ V}$	0.82	0.80	٧
Dynamic <sup>b</sup>	•		•		
Total Gate Charge	Qg	$V_{DS}$ = 15 V, $V_{GS}$ = 4.5 V, $I_{D}$ = 23 A	39	36	nC
Gate-Source Charge	$Q_{gs}$		15	15	
Gate-Drain Charge	$Q_{gd}$		12	12	
Turn-On Delay Time	t <sub>d(on)</sub>	$V_{DD} = 15 \text{ V}, \text{ R}_L = 15 \Omega$ $I_D \cong 1 \text{ A}, \text{ V}_{GEN} = 10 \text{ V}, \text{ R}_G = 6 \Omega$ $I_F = 2.9 \text{ A}, \text{ di/dt} = 100 \text{ A/}\mu\text{s}$	36	20	ns
Rise Time	t <sub>r</sub>		44	15	
Turn-Off Delay Time	t <sub>d(off)</sub>		46	105	
Fall Time	t <sub>f</sub>		74	40	
Source-Drain Reverse Recovery Time	t <sub>rr</sub>		50	50	

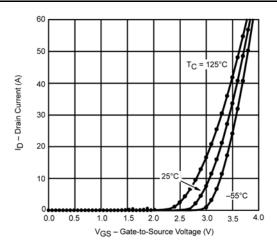
a. Pulse test; pulse width  $\leq$  300  $\mu$ s, duty cycle  $\leq$  2%. b. Guaranteed by design, not subject to production testing.

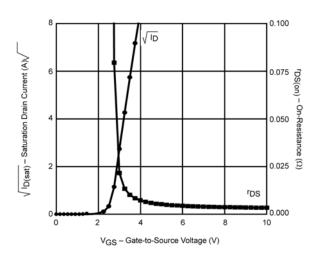


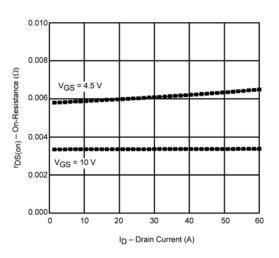
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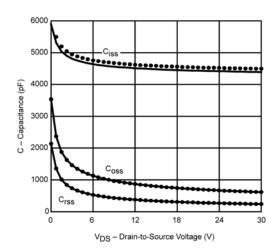
### COMPARISON OF MODEL WITH MEASURED DATA (TJ=25°C UNLESS OTHERWISE NOTED)

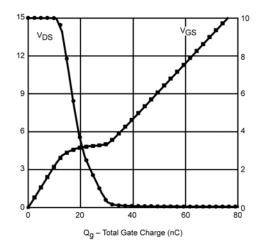












Note: Dots and squares represent measured data.



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Document Number: 91000 Revision: 18-Jul-08

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